

# PG201 - PG2010

С

# FAST RECOVERY RECTIFIER DIODES

## VOLTAGE RANGE: 50-1000V CURRENT: 2.0 A

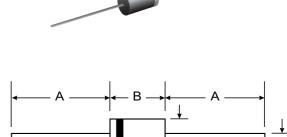
### Features

- Diffused Junction
- Low Forward Voltage Drop
- High Reliability
- High Surge Current Capability

#### **Mechanical Data**

- Case:D O 1 5 Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.40 grams (approx.)
- Mounting Position: Any
- Marking: Type Number





DO-15							
Dim	Min	Max					
Α	25.40	—					
В	5.50	7.62					
С	0.686	0.889					
D	2.60	3.60					
All Dimensions in mm							

Ď

#### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	PG201	PG202	PG203	PG204	PG206	PG208	PG2010	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) $@T_A = 55^{\circ}C$	lo	2.0						А	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	60						А	
Forward Voltage $@I_F = 2.0A$	Vfm	1.2						V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	Irm	5.0 100						μA	
Reverse Recovery Time (Note 2)	trr		1:	50		250	5	00	nS
Typical Junction Capacitance (Note 3)	Cj	30					pF		
Operating Temperature Range	Tj	-65 to +125						°C	
Storage Temperature Range	Тѕтс	-65 to +150					°C		

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.

3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



